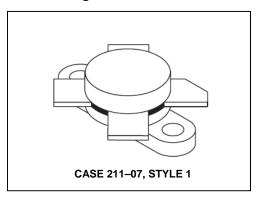


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Designed for high gain driver and output linear amplifier stages in 1.5 to 30 MHz HF/SSB equipment.

- Specified 28 V, 30 MHz characteristics Output power = 25 W (PEP) Minimum gain = 22 dB Efficiency = 35%
- Intermodulation distortion @ 25 W (PEP) —IMD = -30 dB (max)
- 100% tested for load mismatch at all phase angles with 30:1 VSWR
- Class A and AB characterization
- BLX 13 equivalent

#### **Product Image**



#### MAXIMUM RATINGS

Admonitratinos			
Rating	Symbo	l Value	Unit
Collector–Emitter Voltage	V <sub>CEO</sub>	35	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	65	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	4.0	Vdc
Collector Current — Continuous	Ic	3.0	Adc
Withstand Current — 5 s		6.0	Adc
Total Device Dissipation @ T <sub>C</sub> = 25°C (1) Derate above 25°C	P <sub>D</sub>	70 0.4	Watts W/°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R <sub>eJC</sub>	2.5	°C/W

#### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted.)

Symbol	Min	Тур	Max	Unit
	•		•	
V <sub>(BR)CEO</sub>	35	_	_	Vdc
V <sub>(BR)CBO</sub>	65	_	_	Vdc
V <sub>(BR)EBO</sub>	4.0	_	_	Vdc
Ices	_	_	10	mAdc
	V(BR)CEO V(BR)CBO V(BR)EBO	V <sub>(BR)CEO</sub> 35 V <sub>(BR)CBO</sub> 65 V <sub>(BR)EBO</sub> 4.0	V <sub>(BR)CEO</sub> 35 — V <sub>(BR)CBO</sub> 65 — V <sub>(BR)EBO</sub> 4.0 —	V(BR)CEO         35         —         —           V(BR)CBO         65         —         —           V(BR)EBO         4.0         —         —

NOTE:

(continued)

1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

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• North America Tel: 800.366.2266 / Fax: 978.366.2266

### **MRF426**



# The RF Line NPN Silicon Power Transistor 25W(PEP), 30MHz, 28V

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#### ELECTRICAL CHARACTERISTICS — continued (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS	•	•	•	•	
DC Current Gain (I <sub>C</sub> = 1.0 Adc, V <sub>CE</sub> = 5.0 Vdc)	h <sub>FE</sub>	10	35	_	_
DYNAMIC CHARACTERISTICS		•		•	
Output Capacitance (V <sub>CB</sub> = 30 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>ob</sub>	_	60	80	pF
FUNCTIONAL TESTS (SSB)				•	
Common–Emitter Amplifier Gain (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I <sub>CQ</sub> = 25 mA)	G <sub>PE</sub>	22	25	_	dB
Collector Efficiency (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I <sub>CQ</sub> = 25 mA)	η	35	_	_	%
Intermodulation Distortion (2) (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I <sub>CQ</sub> = 25 mA)	IMD <sub>(d3)</sub>	_	-35	-30	dB
Load Mismatch (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I <sub>CQ</sub> = 25 mA, VSWR 30:1 at All Phase Angles)	Ψ	No Degradation in Output Power			
CLASS A PERFORMANCE					
Intermodulation Distortion (2) and Power Gain (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 8.0 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I <sub>CQ</sub> = 1.2 Adc)	G <sub>PE</sub> IMD <sub>(d3)</sub> IMD <sub>(d5)</sub>		23.5 -40 -55		dB

#### NOTE:

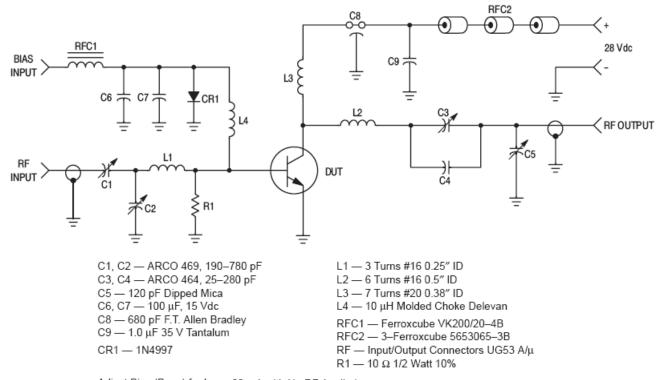
2. To Mil-Std-1311 Version A, Test Method 2204B, Two Tone, Reference each Tone.

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Adjust Bias (Base) for I<sub>CQ</sub> = 20 mA with No RF Applied

Figure 1. 30 MHz Linear Test Circuit

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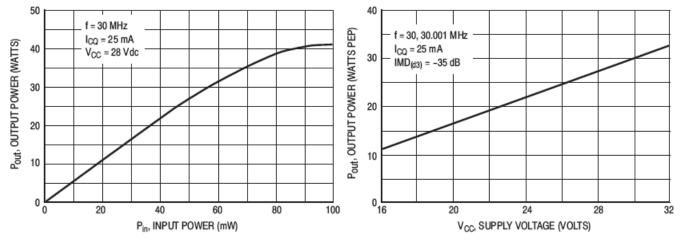


Figure 2. Output Power versus Input Power

Figure 3. Output Power versus Supply Voltage

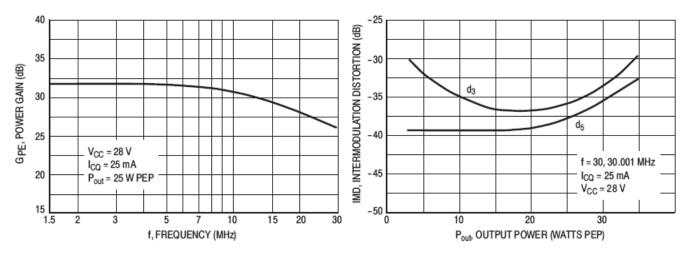


Figure 4. Power Gain versus Frequency

Figure 5. Intermodulation Distortion versus Output Power

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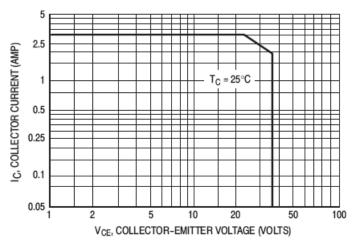


Figure 6. DC Safe Operating Area



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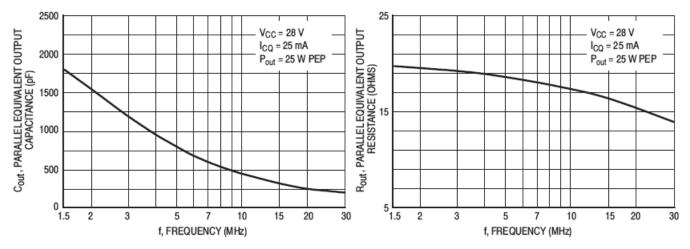


Figure 7. Output Capacitance versus Frequency

Figure 8. Output Resistance versus Frequency

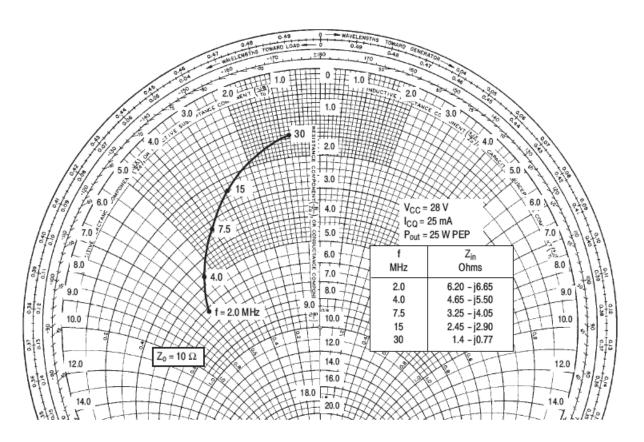
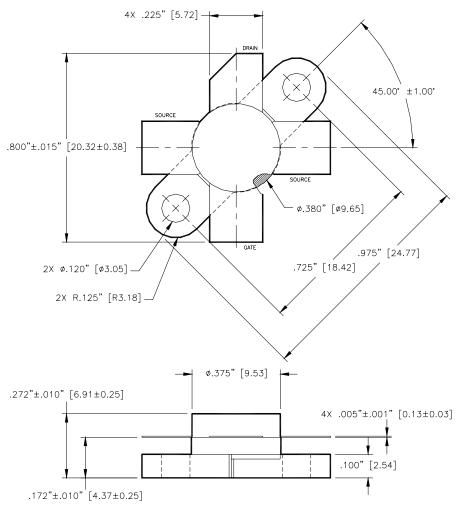


Figure 9. Series Equivalent Input Impedance

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Unless otherwise noted, tolerances are inches  $\pm .005$ " [millimeters  $\pm 0.13$ mm]

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